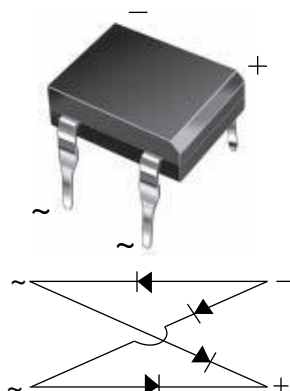




Miniature Glass Passivated Single-Phase Bridge Rectifiers



Case Style DFM

PRIMARY CHARACTERISTICS

Package	DFM
$I_{F(AV)}$	1 A
V_{RRM}	50 V, 100 V, 200 V, 400 V, 600 V, 800 V, 1000 V
I_{FSM}	50 A
I_R	5 μ A
V_F at $I_F = 1.0$ A	1.1 V
T_J max.	150 °C
Diode variations	Quad

FEATURES

- UL recognition, file number E54214
- Ideal for printed circuit boards
- Applicable for automotive insertion
- High surge current capability
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

RoHS
COMPLIANT

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

MECHANICAL DATA

Case: DFM

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked on body

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	DF005M	DF01M	DF02M	DF04M	DF06M	DF08M	DF10M	UNIT
Device marking code		DF005	DF01	DF02	DF04	DF06	DF08	DF10	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward output rectified current at $T_A = 40$ °C	$I_{F(AV)}$	1.0							A
Peak forward surge current single sine-wave superimposed on rated load	I_{FSM}	50							A
Rating for fusing ($t < 8.3$ ms)	I^2t	10							A ² s
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150							°C

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)

PARAMETER	TEST CONDITIONS	SYMBOL	DF005M	DF01M	DF02M	DF04M	DF06M	DF08M	DF10M	UNIT
Maximum instantaneous forward voltage drop per diode	1.0 A	V _F	1.1							V
Maximum reverse current at rated DC blocking voltage per diode	T _A = 25 °C	I _R	5.0							μA
	T _A = 125 °C		500							
Typical junction capacitance per diode	4.0 V, 1 MHz	C _J	25							pF



THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)									
PARAMETER	SYMBOL	DF005M	DF01M	DF02M	DF04M	DF06M	DF08M	DF10M	UNIT
Typical thermal resistance ⁽¹⁾	R _{θJA}	40							°C/W
	R _{θJL}	15							

Note

⁽¹⁾ Thermal resistance from junction to ambient and from junction to lead mounted on PCB with 0.5" x 0.5" (13 mm x 13 mm) copper pads

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
DF06M-E3/45	0.416	45	50	Tube

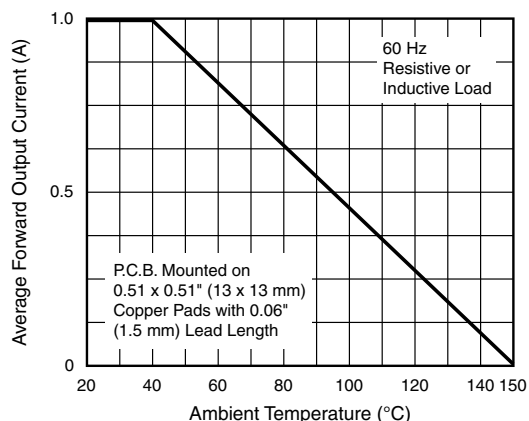
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)


Fig. 1 - Derating Curve Output Rectified Current

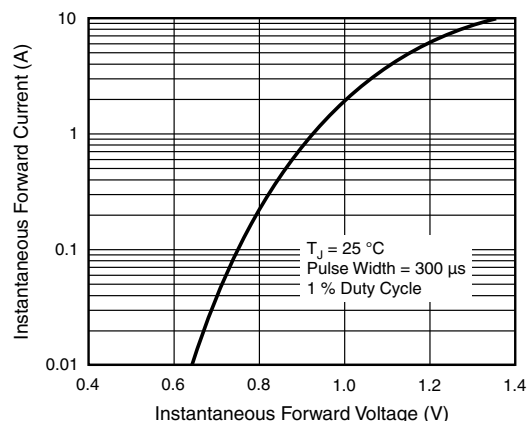


Fig. 3 - Typical Forward Characteristics Per Diode

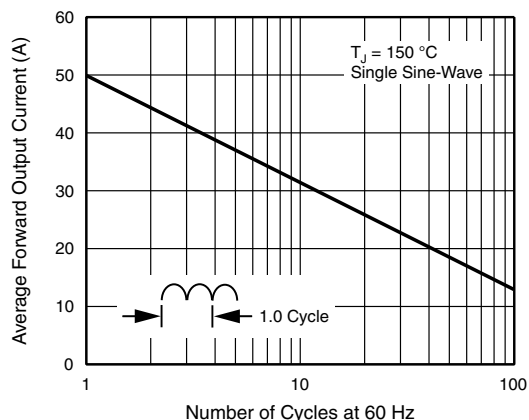


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

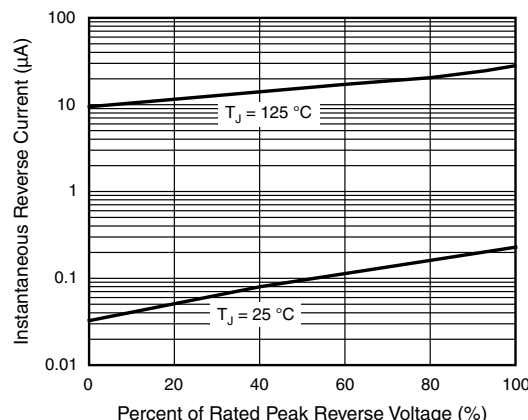


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

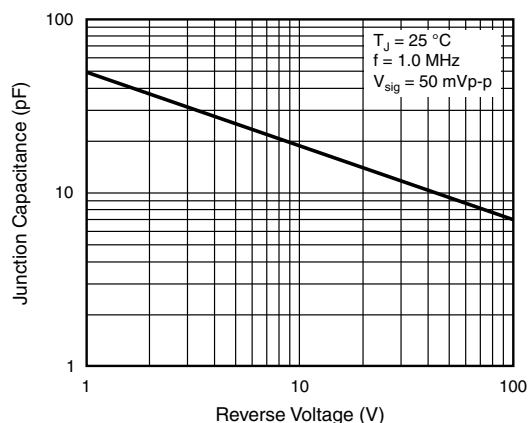


Fig. 5 - Typical Junction Capacitance Per Diode

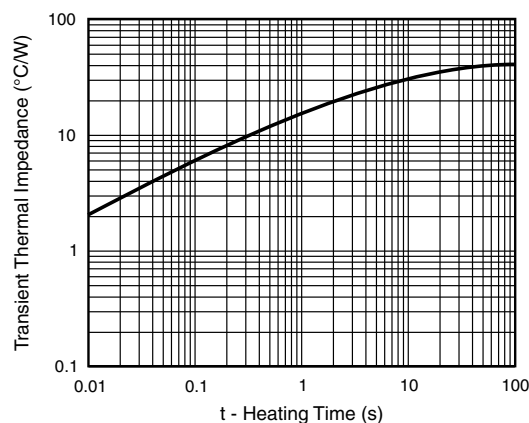


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

Case Style DFM

